

ABF2U THRU ABF10U

Technical Data Data Sheet N1827, Rev. - Green Products

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SINGLE PHASE 1.0AMP SURFACE MOUNT GLASS PASSIVATED BRIDGE RECTIFIER

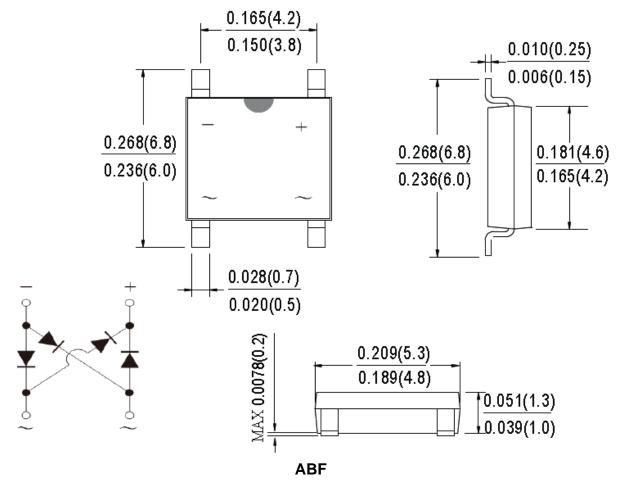
Features:

- Glass passivated die construction
- Low forward voltage drop
- High current capability
- High surge current capability
- Designed for surface mount application
- Plastic material-UL flammability 94V-0

Mechanical Data:

- Case: SOPA-4, Molded plastic ABF
- Terminals: Plated leads solderable per MIL-STD-202, Method 208
- Polarity: Polarity symbols marked on case
- Mounting Position: Any

Mechanical Dimensions: In Inches/mm



China - Germany - Korea - Singapore - United States

http://www.smc-diodes.com - sales@ smc-diodes.com •

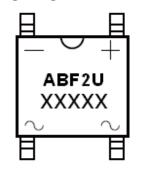




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Marking Diagram:



Where XXXXX is YYWWL

| ABF2U | = Part Name |
|-------|--------------|
| ΥY | = Year |
| WW | = Week |
| L | = Lot Number |

| Cautions: | Molding resin |
|-----------|----------------------|
| | Epoxy resin UL:94V-0 |

Ordering Information:

| Device | Package | Shipping |
|-------------------|-----------|----------------|
| ABF2U THRU ABF10U | ABF | E000pag / rool |
| | (Pb-Free) | 5000pcs / reel |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.



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Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified

Single Phase half wave 60Hz, resistive or inductive load. For capacitive load current derate by 20%.

| Characteristic | Symbol | ABF2U | ABF4U | ABF6U | ABF8U | ABF10U | Units |
|--|---|-------------|-------|-------|-------|------------------|-------|
| Maximum repetitive peak reverse voltage | V_{RRM} | 200 | 400 | 600 | 800 | 1000 | |
| RMS Reverse Voltage | V _{R(RMS)} | 140 | 280 | 420 | 560 | 700 | V |
| Maximum DC blocking voltage | V _{DC} | 200 | 400 | 600 | 800 | 1000 | |
| Average Rectified Output Current @T _c = 100°C | I _{F(AV)} | 1.0 | | | | | V |
| Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method) | I _{FSM} | 35 | | | | А | |
| Rating for fusing (t<8.3ms) | l ² t | 5.08 | | | | A ² s | |
| Forward voltage per element @ $I_F = 0.5A$ @ $I_F = 1.0A$ | V _F | 0.95 1.0 | | | | V | |
| Maximum DC reverse current $T_A = 25^{\circ}C$ at rated DC blocking voltage $T_A = 125^{\circ}C$ | I _R | 5 200 | | | | μA | |
| Typical thermal resistance per leg (Note 1) | $\begin{array}{c} R_{\theta JL} \\ R_{\theta JA} \end{array}$ | 62.5 25 | | | °C/W | | |
| Operating and storage temperature range | T_J, T_{STG} | -55 to +150 | | | °C | | |

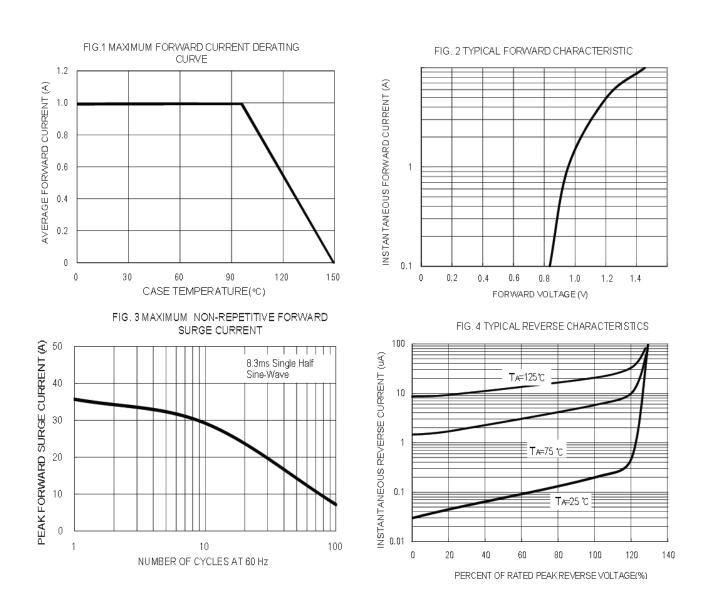
Note: 1. Thermal resistance form junction to ambient and junction to lead mounted on P.C.B. with 0.2X0.2"(5X5mm) copper pads.



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